



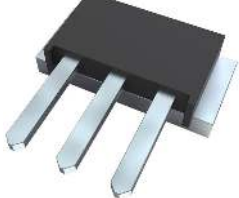
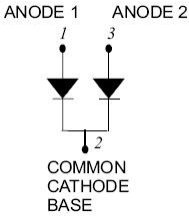
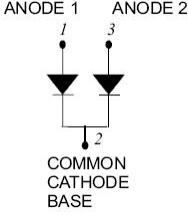
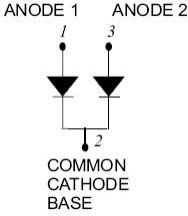
84CNQ060 SCHOTTKY RECTIFIER

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features

- 125°C T_J operation
- Center tap module
- Very Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Low profile, high current package
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

84CNQ060	84CNQ060SL	84CNQ060SM
		
 <p>ANODE 1 ANODE 2 COMMON CATHODE BASE</p>	 <p>ANODE 1 ANODE 2 COMMON CATHODE BASE</p>	 <p>ANODE 1 ANODE 2 COMMON CATHODE BASE</p>
PRM2	PRM2-SL	PRM2-SM

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	60	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C =91°C, rectangular wave form	40(Per Leg) 80(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per leg)	I _{FSM}	8.3 ms, half Sine pulse	750	A
Non-Repetitive Avalanche Energy (Peg leg)	E _{AS}	T _J =25°C, I _{AS} =8A, L=18mH	54	mJ
Repetitive Avalanche Current(Peg leg)	I _{AR}	Current decaying linearly to zero in 1 μsec Frequency limited by T _J max. V _A =1.5×V _R typical	8	A

- China - Germany - Korea - Singapore - United States •
- <http://www.smc-diodes.com> - sales@smc-diodes.com •

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop (Per leg) *	V _{F1}	@ 40A, Pulse, T _J = 25 °C	0.43	0.49	V
		@ 80A, Pulse, T _J = 25 °C	0.52	0.62	
	V _{F2}	@ 40A, Pulse, T _J = 100 °C	0.37	0.44	V
		@ 80A, Pulse, T _J = 100 °C	0.50	0.60	
Reverse Current (Per leg) *	I _{R1}	@V _R = rated VR T _J = 25 °C	4	5	mA
	I _{R2}	@V _R = rated VR T _J = 125 °C	200	600	mA
Junction Capacitance (Per leg)	C _T	@V _R = 5V, T _C = 25 °C f _{sig} = 1MHz	2100	2600	pF

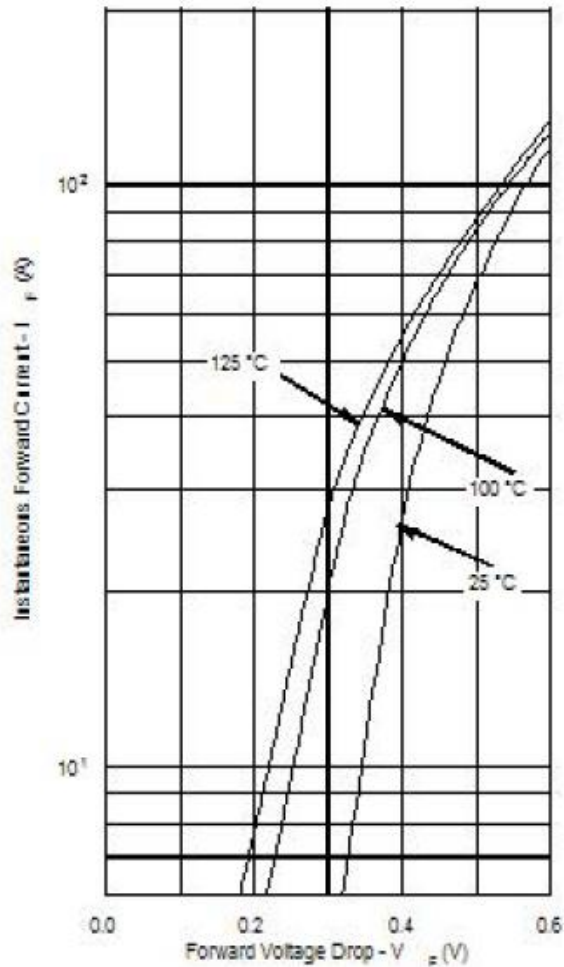
* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications:

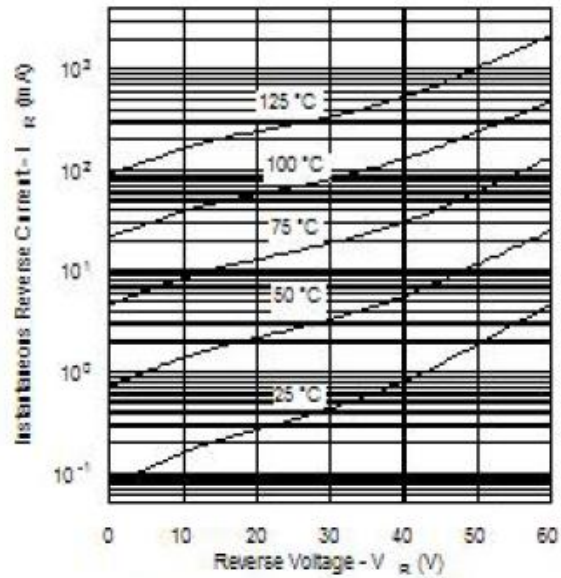
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T _J	-	-55 to +125	°C
Storage Temperature	T _{stg}	-	-55 to +125	°C
Typical Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	0.85	°C/W
Typical Thermal Resistance Junction to Case (per package)	R _{θJC}	DC operation	0.42	°C/W
Typical Thermal Resistance, case to Heat Sink	R _{θcs}	Mounting surface, smooth and greased	0.30	°C/W
Mounting Torque	TM	-	40(min)	Kg-cm
			58(max)	
Approximate Weight	wt	-	7.8	g
Case Style	PRM2 PRM2-SL PRM2-SM			

Ratings and Characteristics Curves

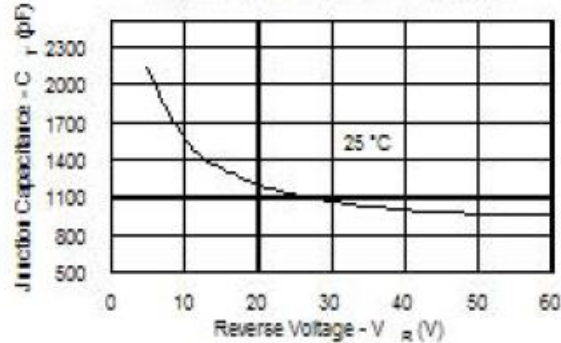
Typical Forward Characteristics



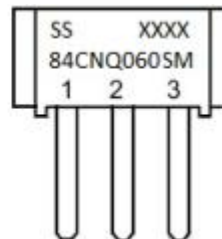
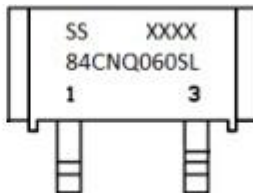
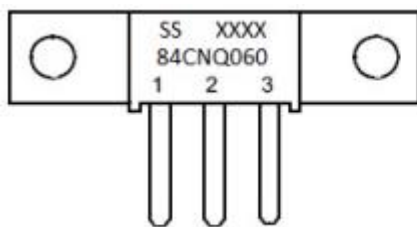
Typical Reverse Characteristics



Typical Junction Capacitance



Marking Diagram



Where XXXX is YYWW

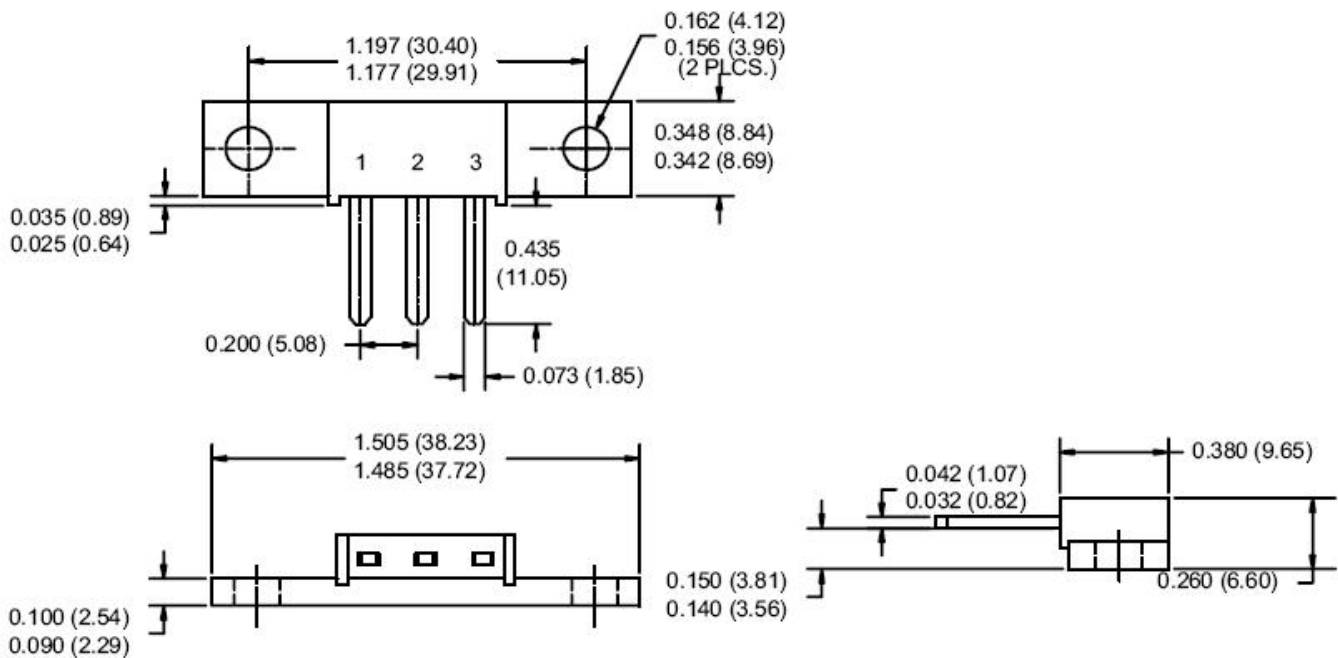
1st row SS YYWWL
2nd row 84CNQ060/SL/SM
3rd row 1 2 3 (pin)
SS = SS
YY = Year
WW = Week

Cautions: Molding resin
Epoxy resin UL:94V-0

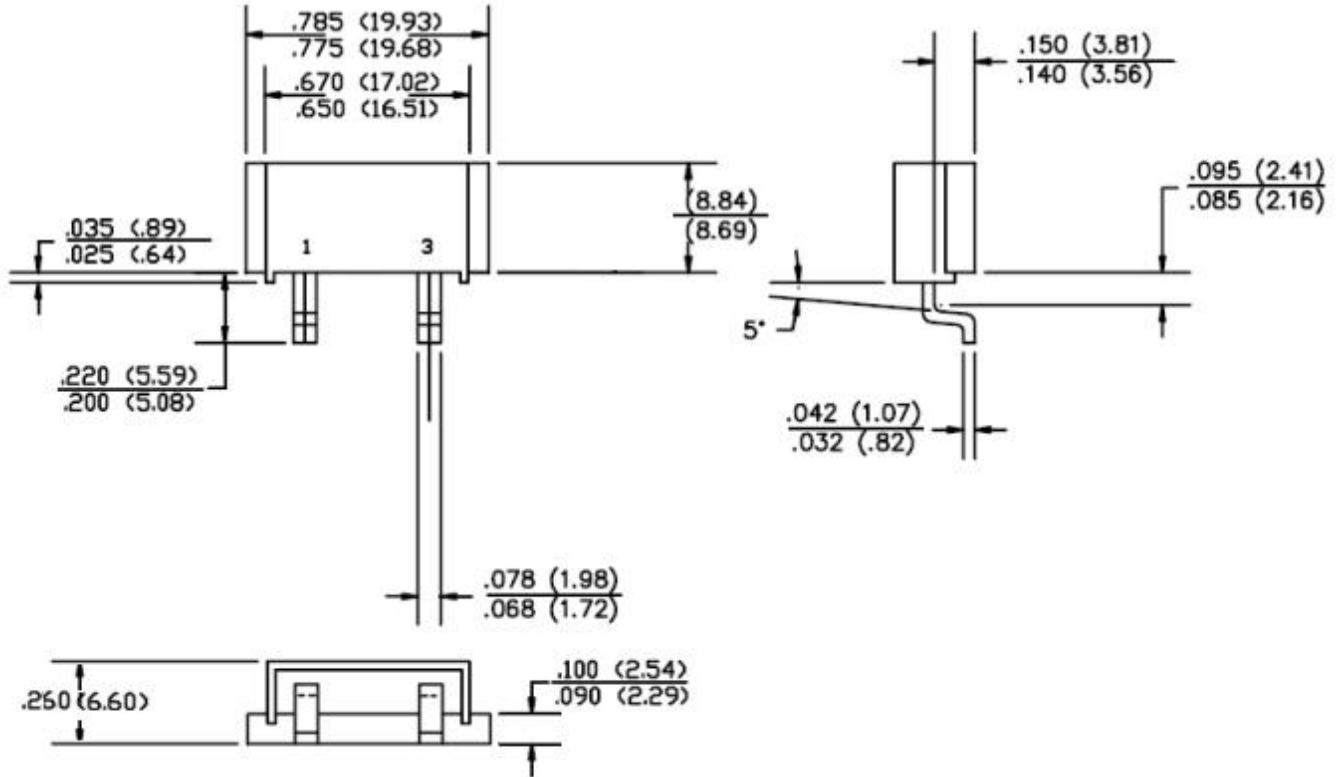
Ordering Information

Device	Package	Terminals finish	Baseplate finish	Shipping
84CNQ060	PRM2	Nickel plated	Nickel plated	48pcs / box
84CNQ060S2	PRM2	Pure Sn dipped (dipped height 6-8mm)	Nickel plated	48pcs / box
84CNQ060SL	PRM2-SL	Pure Sn plated	Pure Sn plated	100pcs / box
84CNQ060SM	PRM2-SM	Nickel plated	Nickel plated	48pcs / box
84CNQ060SMS2	PRM2-SM	Pure Sn dipped (dipped height 6-8mm)	Nickel plated	48pcs / box

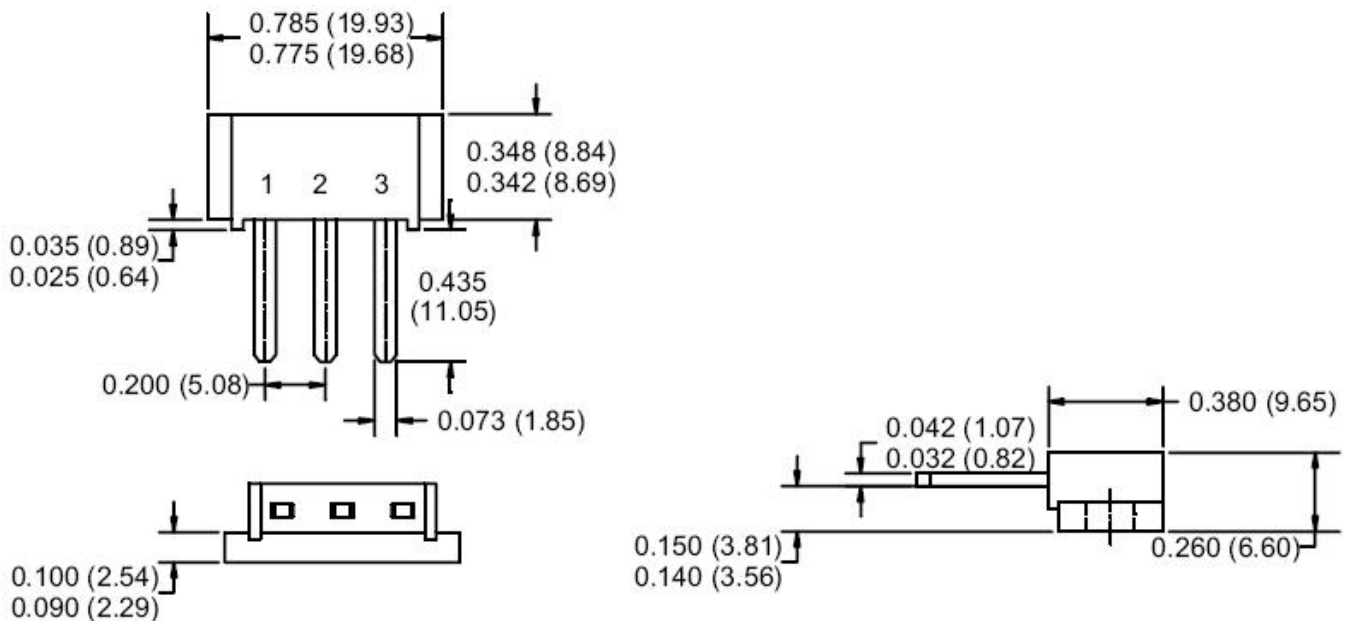
Mechanical Dimensions PRM2 (Inches/Millimeters)



Mechanical Dimensions PRM2-SL (Inches/Millimeters)



Mechanical Dimensions PRM2-SM (Inches/Millimeters)





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